

DS1692/DS3692 TRI-STATE® Differential Line Drivers

General Description

The DS1692/DS3692 are low power Schottky TTL line drivers electrically similar to the DS1691A/DS3691 but tested to meet the requirements of MIL-STD-188-114A (see Application Note AN-216). MIL-STD-188-114A type 1 driver specifications can be met by adding an external three resistor voltage divider to the output of the DS3692/1692. The DS3692/1692 feature 4 buffered outputs with high source and sink current capability with internal short circuit protection.

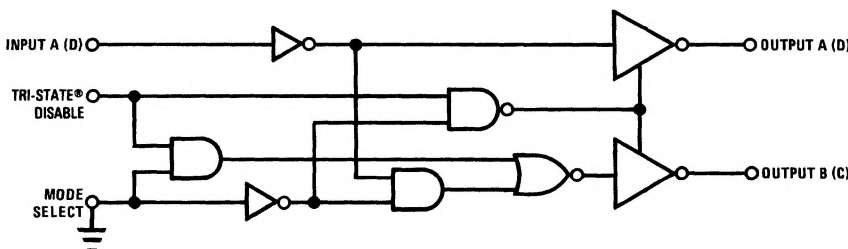
With the mode select pin low, the DS1692/DS3692 are dual differential line drivers with TRI-STATE outputs. They feature $\pm 10V$ output common-mode range in TRI-STATE and 0V output unbalance when operated with $\pm 5V$ supply.

Multipoint applications in differential mode with waveshaping capacitors is not allowed.

Features

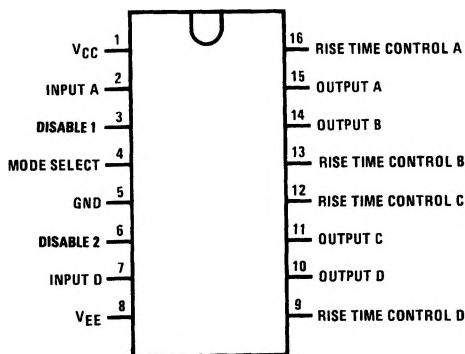
- Short circuit protection for both source and sink outputs
- 100Ω transmission line drive capability
- Low I_{CC} and I_{EE} power consumption
 - Differential mode $I_{CC} = 9 \text{ mA/driver typ}$
 - $I_{EE} = 5 \text{ mA/driver typ}$
- Low current PNP inputs compatible with TTL, MOS and CMOS
- Adaptable as MIL-STD-188-114A type 1 driver

Logic Diagram (1/2 Circuit Shown)



TL/F/5784-1

Connection Diagram



TL/F/5784-2

Top View

Order Number DS1692J, DS3692J,
DS3692M or DS3692N

See NS Package Number J16A, M16A* or N16A

*Contact Product Marketing for availability.

Truth Table

Mode	Inputs		Outputs	
	A (D)	Disable1 (2)	A (D)	B (C)
0	0	0	0	1
0	0	1	TRI-STATE	TRI-STATE
0	1	0	1	0
0	1	1	TRI-STATE	TRI-STATE

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	
V _{CC}	7V
V _{EE}	-7V
Maximum Power Dissipation* at 25°C	
Cavity Package	1509 mW
Molded Package	1476 mW
Input Voltage	15V
Output Voltage (Power OFF)	±15V
Storage Temperature	-65°C to +150°C
Lead Temperature (Soldering, 4 sec.)	260°C

*Derate cavity package 10.1 mW/°C; derate molded package 11.9 mW/°C above 25°C.

Operating Conditions

	Min	Max	Units
Supply Voltage			
DS1692			
V _{CC}	4.5	5.5	V
V _{EE}	-4.5	-5.5	V
DS3692			
V _{CC}	4.75	5.25	V
V _{EE}	-4.75	-5.25	V
Temperature (T _A)			
DS1692	-55	+125	°C
DS3692	0	+70	°C

Electrical Characteristics DS1692/DS3692 (Notes 2, 3 and 4)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
DS1692, V_{CC} = 5V ± 10%, DS3692, V_{CC} = 5V ± 5%, V_{EE} CONNECTION TO GROUND, MODE SELECT ≤ 0.8V						
V _O V _O	Differential Output Voltage V _{A,B}	R _L = ∞	V _{IN} = 2V	2.5	3.6	V
			V _{IN} = 0.8V	-2.5	-3.6	V
V _T V _T	Differential Output Voltage V _{A,B}	R _L = 100Ω V _{CC} ≥ 4.75V	V _{IN} = 2V	2	2.6	V
			V _{IN} = 0.8V	-2	-2.6	V
V _{OS} , V _{OS}	Common-Mode Offset Voltage	R _L = 100Ω		2.5	3	V
V _T - V _T	Difference in Differential Output Voltage	R _L = 100Ω		0.05	0.4	V
V _{OS} - V _{OS}	Difference in Common-Mode Offset Voltage	R _L = 100Ω		0.05	0.4	V
V _{SS}	V _T - V _T	R _L = 100Ω, V _{CC} ≥ 4.75V	4.0	4.8		V
I _{OX}	TRI-STATE Output Current	V _O ≤ -10V		-0.002	-0.15	mA
		V _O ≥ 15V		0.002	0.15	mA
I _{SA}	Output Short Circuit Current	V _{IN} = 0.4V	V _{OA} = 6V	80	150	mA
			V _{OB} = 0V	-80	-150	mA
I _{SB}	Output Short Circuit Current	V _{IN} = 2.4V	V _{OA} = 0V	-80	-150	mA
			V _{OB} = 6V	80	150	mA
I _{CC}	Supply Current			18	30	mA
DS1692, V_{CC} = 5V ± 10%, V_{EE} = -5V ± 10%, DS3692, V_{CC} = 5V ± 5%, V_{EE} = -5 ± 5%, MODE SELECT ≤ 0.8V						
V _O V _O	Differential Output Voltage V _{A,B}	R _L = ∞	V _{IN} = 2.4V	7	8.5	V
			V _{IN} = 0.4V	-7	-8.5	V
V _T V _T	Differential Output Voltage V _{A,B}	R _L = 200Ω	V _{IN} = 2.4V	6	7.3	V
			V _{IN} = 0.4V	-6	-7.3	V
V _T - V _T	Output Unbalance	V _{CC} = V _{EE} , R _L = 200Ω		0.02	0.4	V
I _{OX}	TRI-STATE Output Current		V _O = 10V	0.002	0.15	mA
			V _O = -10V	-0.002	-0.15	mA
I _S ⁺ I _S ⁻	Output Short Circuit Current	V _O = 0V	V _{IN} = 2.4V	-80	-150	mA
			V _{IN} = 0.4V	80	150	mA
I _{SLEW}	Slew Control Current			±140		μA
I _{CC}	Positive Supply Current	V _{IN} = 0.4V, R _L = ∞		18	30	mA
I _{EE}	Negative Supply Current	V _{IN} = 0.4V, R _L = ∞		-10	-22	mA

Electrical Characteristics (Notes 2 and 3) $V_{EE} \leq 0V$

Symbol	Parameter	Conditions	Min	Typ	Max	Units
V_{IH}	High Level Input Voltage		2			V
V_{IL}	Low Level Input Voltage				0.8	V
I_{IH}	High Level Input Current	$V_{IN} = 2.4V$		1	40	μA
		$V_{IN} \leq 15V$		10	100	μA
I_{IL}	Low Level Input Current	$V_{IN} = 0.4V$		-30	-200	μA
V_I	Input Clamp Voltage	$I_{IN} = -12 mA$			-1.5	V
I_{XA} I_{XB}	Output Leakage Current Power OFF	$V_{CC} = V_{EE} = 0V$	$V_O = 15V$	0.01	0.15	mA
			$V_O = -15V$	-0.01	-0.15	mA

Switching Characteristics $T_A = 25^\circ C$

Symbol	Parameter	Conditions	Min	Typ	Max	Units
$V_{CC} = 5V$, $MODE\ SELECT = 0.8V$						
t_r	Differential Output Rise Time	$R_L = 100\Omega$, $C_L = 500 pF$ (Figure 1)		120	200	ns
t_f	Differential Output Fall Time	$R_L = 100\Omega$, $C_L = 500 pF$ (Figure 1)		120	200	ns
t_{PDH}	Output Propagation Delay	$R_L = 100\Omega$, $C_L = 500 pF$ (Figure 1)		120	200	ns
t_{PDL}	Output Propagation Delay	$R_L = 100\Omega$, $C_L = 500 pF$ (Figure 1)		120	200	ns
t_{PZL}	TRI-STATE Delay	$R_L = 100\Omega$, $C_L = 500 pF$ (Figure 2)		180	250	ns
t_{PZH}	TRI-STATE Delay	$R_L = 100\Omega$, $C_L = 500 pF$ (Figure 2)		180	250	ns
t_{PLZ}	TRI-STATE Delay	$R_L = 100\Omega$, $C_L = 500 pF$ (Figure 2)		80	150	ns
t_{PHZ}	TRI-STATE Delay	$R_L = 100\Omega$, $C_L = 500 pF$ (Figure 2)		80	150	ns
$V_{CC} = 5V$, $V_{EE} = -5V$, $MODE\ SELECT = 0.8V$						
t_r	Differential Output Rise Time	$R_L = 200\Omega$, $C_L = 500 pF$ (Figure 1)		190	300	ns
t_f	Differential Output Fall Time	$R_L = 200\Omega$, $C_L = 500 pF$ (Figure 1)		190	300	ns
t_{PDL}	Output Propagation Delay	$R_L = 200\Omega$, $C_L = 500 pF$ (Figure 1)		190	300	ns
t_{PDH}	Output Propagation Delay	$R_L = 200\Omega$, $C_L = 500 pF$ (Figure 1)		190	300	ns
t_{PZL}	TRI-STATE Delay	$R_L = 200\Omega$, $C_L = 500 pF$ (Figure 2)		180	250	ns
t_{PZH}	TRI-STATE Delay	$R_L = 200\Omega$, $C_L = 500 pF$ (Figure 2)		180	250	ns
t_{PLZ}	TRI-STATE Delay	$R_L = 200\Omega$, $C_L = 500 pF$ (Figure 2)		80	150	ns
t_{PHZ}	TRI-STATE Delay	$R_L = 200\Omega$, $C_L = 500 pF$ (Figure 2)		80	150	ns

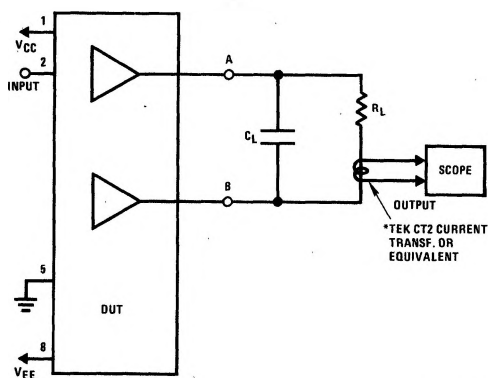
Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provide conditions for actual device operation.

Note 2: Unless otherwise specified, min/max limits apply across the $-55^\circ C$ to $+125^\circ C$ temperature range for the DS1692 and across the $0^\circ C$ to $+70^\circ C$ range for the DS3692. All typicals are given for $V_{CC} = 5V$ and $T_A = 25^\circ C$. V_{CC} and V_{EE} as listed in operating conditions.

Note 3: All currents into device pins are positive; all currents out of device pins are negative. All voltages are referenced to ground unless otherwise specified.

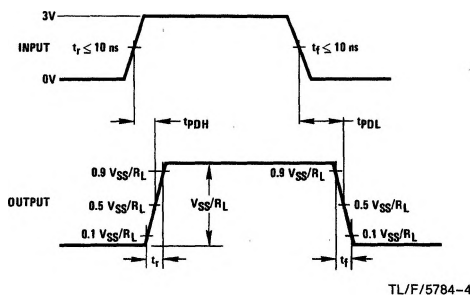
Note 4: Only one output at a time should be shorted.

AC Test Circuits and Switching Time Waveforms

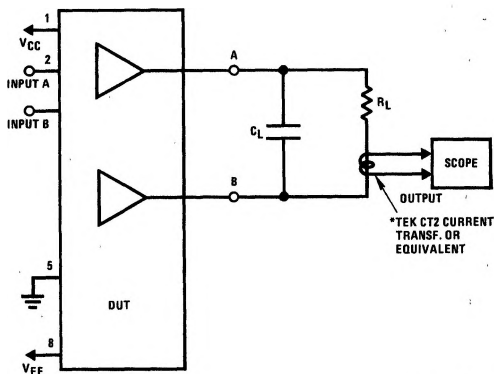


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FIGURE 1. Differential Connection

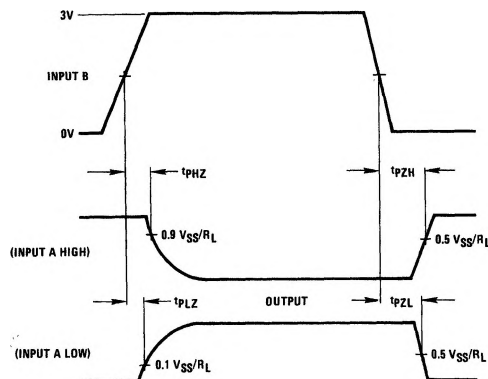


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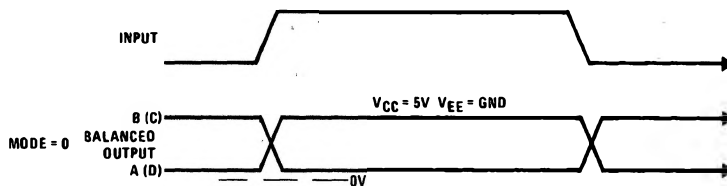
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FIGURE 2. TRI-STATE Delays for DS1692/DS3692

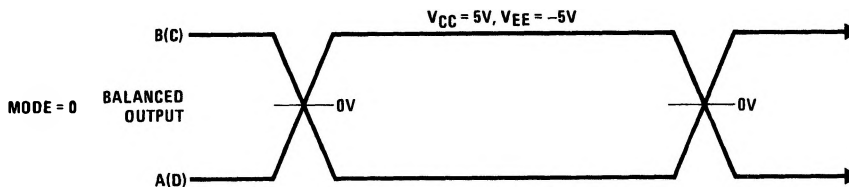


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Switching Waveforms



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